DRFS Development

KEK S. Fukuda

- Introduction : DRFS R&D Plan
- Talks concerning with DRFS in LCWS10 in Beijing
- Concept of DRFS
- R&D Plan for DRFS in KEK
- Summary

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Introduction : DRFS R&D Plan in KEK

- DRFS Plan is supported in ASIAN ILC project, especially it is matched with Japan site condition.
- For S1 global in end of 2010, budget of 2-klystron DRFS system are approved or will be approved).
- For STF phase-II project in 2013, DRFS system for 1 full cryomodule, i.e., 4-5 klystron DRFS system, is strongly supported.
- For these periods, study of DRFS basic configuration are performed.
- Critical issues such as the reliability of the over-current protection HV relay or switch and crowbar protection are intensively studied.
- Cost related study of klystron are now under consideration.

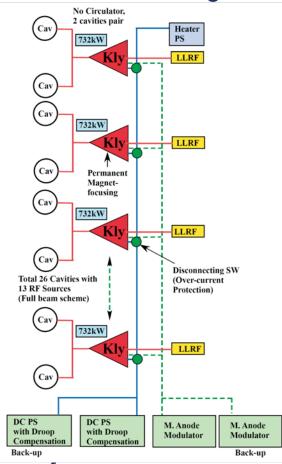
•	S. Fukuda	DRFS Equipment	Joint CFS	March 27 am
•	S. Fukuda	CFS matter: Layout, Cooling DRFS Developmen		March 27 pm
	M. Akemoto(V	This presentation Vebex) Power supp Power Supply System R&D	•	March 27 pm
•	S. Michizono S. Fukuda	DRFS LLRF system S1-Global RF Prepa	n configuration	March 27 pm March 29 am
	S. Michizono	S1-Global study pla	เท	March 29 pm



Concept of DRFS

Concept of DRFS

- The Distributed RF System (DRFS) is another possibility for a costeffective solution in support of a single Main Linac tunnel design.
- Base line of proposed DRFS
 - one unit of 750kW Modulating Anode (MA) klystron would drive two cavities (in basic configuration scheme –BCS/HCS).
 - totally about 8000 MA klystrons would be used.
 - It is based on much simpler and more compact HLRF and LLRF units than the RDR baseline or KCS.
 - It offers a good operational flexibility in coupling with performance variations of individual cavities.
 - By employing suitable back-up modules for key component, high availability would be expected.
 - Complete single tunnel model, no facility in the surface



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Parameters in DRFS

In the RDR scheme, three units of ILC cryomodules, containing 26 cavities in total, are driven by the RF power from one unit of 10MW L-band klystron.

In the proposed new scheme of DRFS, 2 cavities are driven by one unit of 750kW L-band MA klystron. Therefore, one would see that three cryomodules with 26 cavities will be driven by thirteen units of MA klystrons.

KlystronFrequency1.3GHzPeak Power750kWAverage Power Output7.50kWRF pulse width1.5msRepitition Rate5HzEfficiency60%Saturated GainCathode voltage64.1kVCathode current19.5APerveance(Beam@64.1kV)1.2mPerv(Gun@53kV)1.56mPervLife Time120,000hours# in 3 cryomodule13FocusingPermanent magnetType of KlystronModulated Anode TypeDC Power supply per 3 cryomodules71.5kVPeak Pulse Current2.47AAverage Current2.47AOutput Power177kWPulse width2.2msRepitition Rate5HzVoltage Sag<1%Capacitor26mFBouncer Circuit260mFM. Anode Modulator4.9mHM. Anode Modulator2.474.9M. Anode Bias Voltage53kV								
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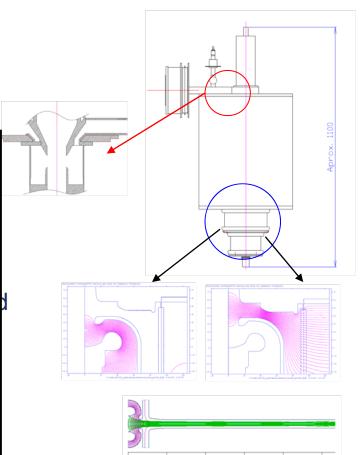
Klystron for DRFS

Parameters of MA klystron is summarized In the previous table.

Features of DRFS klystron

Applied voltage of less than 65kV 60% efficiency with 1.2 microperveance Low field gradient in klystron gun —few arcing Low cathode loading--- long cathode life Low output power--- free from output window failure Long life of klystron would be expected

Permanent magnet focusing--- free from magnet and power supply failure Common heater power supply with back-up --- contribute to high availability



Modulator Scheme/Base Line DRFS

• The DC power and anode modulation for a group of 13 units of klystrons are provided by one common DC power supply and one common anode modulator (MA modulator).

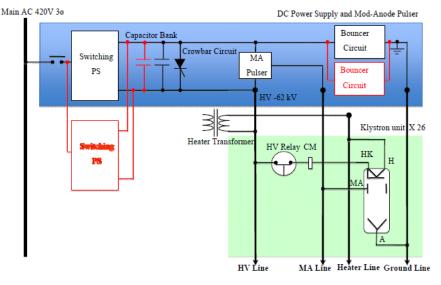
• In order to realize high reliability, each of the DC power supplies and MA modulators is associated with one backup units, which will be designed and implemented to be "hot-swappable".

• Each of the power and voltage distribution circuits will have a high-voltage SW or relay, which switches off the line when over current failures are detected.

• A DC power supplies has a bouncer circuit for compensation of the pulse flat droop. (This leads to a relatively small condenser bank)

- The charger of a DC power supply comprises of a bundle of several units of identical switching PS. This allows us to increase its electrical power with ease, simply by adding more switching PS.
- Common heater power supply and permanent magnet focusing to eliminating magnet power supply.

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Power Distribution System (PDS)

Very simple power distribution system

- No circulator
- Power divider employs magic tee with high isolation for space saving.
- One Phase-shifter with symmetric PDS between couplers or asymmetric PDS with a phase-fixed waveguide for cost saving
- Modification of cavity interval helps greatly for the PDS of DRFS.
- Design of eliminating flange as possible leads to the cost reduction.
- 750kW RF is propagated in the dry air without any extra ceramic window



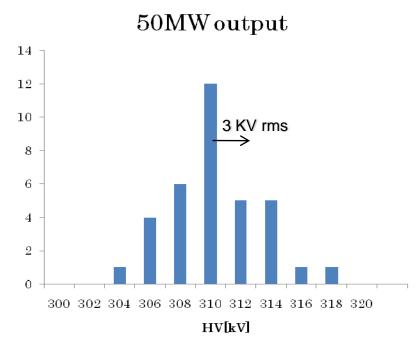
DRFS Basic PDS (HCS)

Cavity Pairing Scheme in DRFS

- We permit that SCRF Cavity Property varies 31.5 MV/m+-20%. This means from 25MV/m to 38MV/m.
- In DRFS, baseline doesn't use circulator and in order to accept above variety, cavity pairing scheme of having almost the same gradient is required.

- From the HLRF viewpoint, most severe condition is come from the pair of 38MV/m cavities, while 770kW output from the DRFS klystron can drive the pair of 38MV/m cavities if 15% overhead of rf is allowed.
- Considering the klystron yield rate, proper combination of klystron variation and cavity variation result in efficient application of resources.

HLRF requirements



KEKB injector klystrons (40 MW and 50
 MW) are statistically analysed.
 Klystrons have 1.2% (40 MW) and 1%

(50 MW) rms HV distribution to reach 40 or 50 MW.

These correspond to ~3% power distribution with same HV. (P~V^2.5)

Suppose the cavity distribution is 3 MV/m rms (~10%), 770kW klystrons can drive 38 MV/m cavities with 15% rf overhead.

				10%sigma cavities			
				31.5	0.5		4000
35				32	0.563059	0.063059	504.4741
	3%sigma Kly	/stron		33	0.683031	0.119971	959.7712
34	0.158655254			34	0.786301	0.10327	826.1597
35	0.5		4000	35	0.86674	0.080439	643.5129
36	0.841344746	0.341345	2730.758	36	0.923436	0.056697	453.5723
37	0.977249868	0.135905	1087.241	37	0.959597	0.036161	289.2881
38	0.998650102	0.0214	171.2019	38	0.980467	0.02087	166.9581

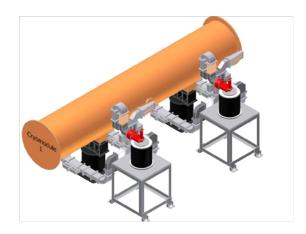
LCWS10 in Beijing 11 DRFS Development (S. Fuk@da)meeting Beijing (Mar.27, 2010)



R&D Plan for DRFS in KEK

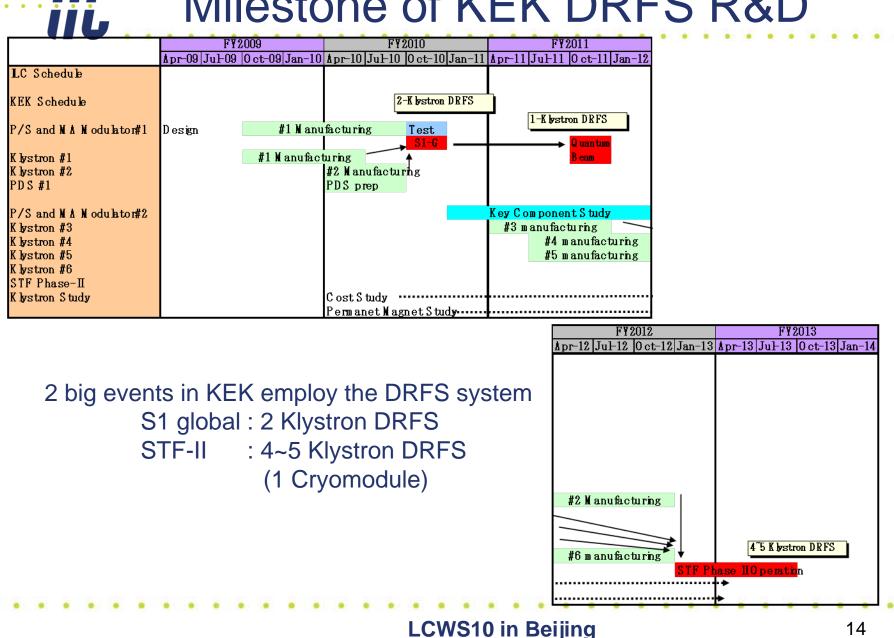
Task and R & D schedule of DRFS in KEK

- •R&D study is easy since the DRFS system is not large.
- •Task force team of DRFS starts and try to solve the problems of DRFS.
- •Prototype RF unit is manufactured in FY09
- •Further R&D required for the DRFS RF system is continued from FY09. Three year R&D budget was approved.
- •Permanent magnet, high voltage SW and IGBT will be studied intensively.
- •Prototype will be evaluated in the S1 global test (2 Klystron DRFS)
- •And then installed in the buncher section of STF-II aiming for the realistic operation.
- •More large scale of DRFS (4~5 Klystron DRFS) is planed for STF-II in KEK.



S1-Global Plan

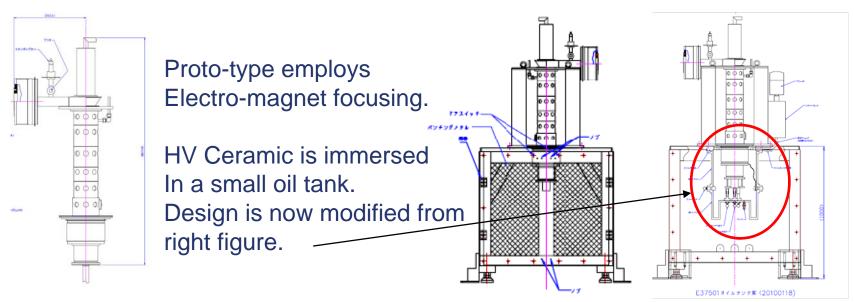
Milestone of KEK DRFS R&D



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Prototype DRFS Klystron (S1-G)

- For S1-global demonstration, KEK will order 2 DRFS klystrons.
- A prototype klystron was ordered in FY09 and will be delivered in around August of 2010. Another klystron will be ordered in April of 2010 and we expect to finish basic performance test till middle of November. Two klystrons and a MA modulator are installed S1-global bench on December and tested.



DRFS klystron

Socket Assembly of DRFS klystron

DRFS Power Supply/Modulator

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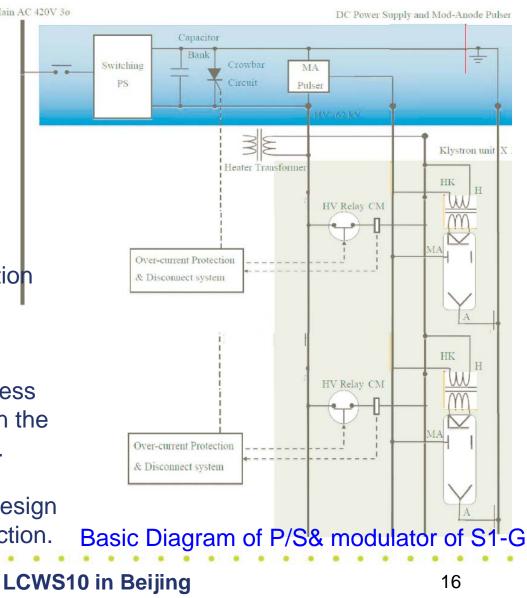
In FY09, prototype DC modulator Main AC 420V 30 And MA modulator are ordered.

Capability for 2 klystron loads

Due to small budget, bouncer circuit are not used in S1-G. Compensation of sag for RF is covered by LLRF feedback. (If this attempt is successful, reduction of capacitors are benefit for cost).

Crowbar circuit using thyratron is introduced. Possibility for crowbar-less is tested. This is strongly depend on the klystron durability for HV discharge.

MA modulator is based on J-Parc design and studied the shunt resistor reduction. (strong effect for cost)



27/03/2010

- R&D plan of Distributed RF Scheme (DRFS) is presented.
- 2-klystron DRFS is almost approved and is demonstrated in S1- global test.
- 4 (5)- klystron DRFS is strongly supported for STF-phase II in 2013 and R&D plan is under establishing.
- A prototype DRFS klystron is now manufacturing.
- A prototype power supply is also under manufacturing.
- Several R&D key issues are descrived.

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